

<<微电子专业英语>>

图书基本信息

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作者：吕红亮 等编著

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内容概要

本书以英文的形式介绍了微电子学和集成电路设计的相关技术。全书共分四部分：第一部分为半导体物理基础知识，包括晶格结构、能带结构、载流子浓度和输运等；第二部分介绍半导体器件物理基础理论，包括pn结、肖特基二极管、异质结二极管、双极型晶体管和场效应晶体管；第三部分简要阐述半导体集成电路的设计过程和设计方法；第四部分介绍半导体集成电路的制造工艺。

本书可作为高等学校微电子学、集成电路设计及相关专业的“专业英语”课程的教材，也可作为从事微电子和集成电路相关科研和工程技术人员的参考书。

<<微电子专业英语>>

书籍目录

- Session 1 Introduction to Semiconductor
 - 1.1 What is Semiconductor
 - 1.2 Classification of Semiconductor
 - Reading Materials
- Session 2 Crystal Structure
 - 2.1 Primitive Cell and Crystal Plane
 - 2.2 Atomic Bonding
 - Reading Materials
- Session 3 Band Model
 - 3.1 Introduction to Quantum Mechanics
 - 3.2 Band
 - 3.3 Effective Mass Theory
 - Reading Materials
- Session 4 The Semiconductor in Equilibrium
 - 4.1 Charge Carriers in Semiconductor
 - 4.2 Intrinsic Semiconductor
 - 4.3 Extrinsic Semiconductor
 - Reading Materials
- Session 5 Carrier Transport
 - 5.1 Overview of Carrier Transport
 - 5.2 Low Field Transport
 - 5.3 High Field Transport
 - 5.4 Diffusion Current
- Session 6 Nonequilibrium Excess Carriers in Semiconductor
 - 6.1 Recombination??
 - 6.2 Minority Carrier Lifetime
 - 6.3 Ambipolar Transport
 - Reading Materials
- Session 7 The pn Junction ()
 - 7.1 Introduction
 - 7.2 Basic Structure of the pn Junction
 - 7.3 Energy Bands for a pn Junction
 - 7.4 Ideal Current?Voltage Relationship
 - 7.5 Characteristics of a Practical Diode
 - Reading Materials
- Session 8 The pn Junction ()
 - 8.1 Breakdown in pn Junction
 - 8.2 Small?Signal Diffusion Resistance of the pn Junction
 - 8.3 Junction Capacitance
 - 8.4 Diffusion or Storage Capacitance
 - 8.5 Diode Transients
 - 8.6 Circuit Models for Junction Diodes
 - Reading Materials
- Session 9 Metal?Semiconductor Contacts
 - 9.1 Schottky Contacts

<<微电子专业英语>>

9.2 Ohmic Contacts

Reading Materials

Session 10 Heterojunctions

10.1 Strain and Stress at Heterointerfaces

10.2 Heterojunction Materials

10.3 Energy?Band Diagrams

Reading Materials.

Session 11 The Bipolar Junction Transistor ()

11.1 The Bipolar Junction Transistor Construction

11.2 Transistor Action

11.3 Nonideal Effects

11.4 Base Resistance

Reading Materials

Session 12 The Bipolar Junction Transistor ()

12.1 Breakdown Voltage

12.2 Frequency Limits of BJT

12.3 The Schottky?Clamped Transistor

12.4 Small?signal Transistor Model

Reading Materials

Session 13 Basics of MOSFETs

13.1 Introduction

13.2 General Characteristics of a MOSFET

13.3 MOS System

13.4 Work Function Differences

13.5 Flat?Band Voltage

13.6 Threshold Voltage

Reading Materials

Session 14 Nonideal Effects of MOSFETs

14.1 Introduction

14.2 Effective Mobility

14.3 Velocity Saturation

14.4 Channel?length Modulation

14.5 DIBL

14.6 Hot?carrier Effect

14.7 GIDL

Reading Materials

Session 15 Advanced MOSFET Devices

15.1 Introduction

15.2 Channel Doping Profile

15.3 Gate Stack

15.4 Source/Drain Design

15.5 Schottky?Barrier Source/Drain

15.6 Raised Source/Drain

15.7 SOI

15.8 Three Dimensional Structure

Reading Materials

Session 16 Introduction to Integrated Circuits

<<微电子专业英语>>

- 16.1 Introduction
- 16.2 Size and Complexity of Integrated Circuits
- 16.3 Semiconductor Device for Integrated Circuits
- 16.4 IC Design Process

Reading Materials

Session 17 Analog Integrated Circuits Design

- 17.1 Introduction
- 17.2 Analog Signal Processing
- 17.3 CMOS Technology
- 17.4 Amplifiers
- 17.5 Differential Amplifiers
- 17.6 Operational Amplifiers
- 17.7 Characterization of Op Amps

Reading Materials

Session 18 Digital Integrated Circuits Design

- 18.1 Introduction
- 18.2 The Static CMOS Inverter
- 18.3 Designing Combinational Logic Gates in CMOS

Reading Materials

Session 19 Radio Frequency Integrated Circuits Design

- 19.1 Introduction
- 19.2 RF System Performance Metrics
- 19.3 RF Transceiver Architectures
- 19.4 RF Passive Component

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